

## MCR68-2

### Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.0	$^{\circ}C/W$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	60	$^{\circ}C/W$
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	$T_L$	260	$^{\circ}C$

### Electrical Characteristics ( $T_C = 25^{\circ}C$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
----------------	--------	-----	-----	-----	------

#### OFF CHARACTERISTICS

Peak Repetitive Forward or Reverse Blocking Current ( $V_{AK} = \text{Rated } V_{DRM} \text{ or } V_{RRM}, \text{ Gate Open}$ )	$I_{DRM}, I_{RRM}$	-	-	10	$\mu A$
	$T_J = 25^{\circ}C$	-	-	2.0	$\mu A$
	$T_J = 125^{\circ}C$	-	-	2.0	$\mu A$

#### ON CHARACTERISTICS

Peak Forward On-State Voltage ( $I_{TM} = 24 \text{ A}$ ) (Note 3) ( $I_{TM} = 300 \text{ A}, t_w = 1 \text{ ms}$ ) (Note 4)	$V_{TM}$	-	-	2.2	V
		-	6.0	-	
Gate Trigger Current (Continuous dc) ( $V_D = 12 \text{ V}, R_L = 100 \Omega$ )	$I_{GT}$	2.0	7.0	30	mA
Gate Trigger Voltage (Continuous dc) ( $V_D = 12 \text{ V}, R_L = 100 \Omega$ )	$V_{GT}$	-	0.65	1.5	V
Gate Non-Trigger Voltage ( $V_D = 12 \text{ Vdc}, R_L = 100 \Omega, T_J = 125^{\circ}C$ )	$V_{GD}$	0.2	0.40	-	V
Holding Current ( $V_D = 12 \text{ V}, \text{ Initiating Current} = 200 \text{ mA}, \text{ Gate Open}$ )	$I_H$	3.0	15	50	mA
Latching Current ( $V_D = 12 \text{ Vdc}, I_G = 150 \text{ mA}$ )	$I_L$	-	-	60	mA
Gate Controlled Turn-On Time (Note 5) ( $V_D = \text{Rated } V_{DRM}, I_G = 150 \text{ mA}$ ) ( $I_{TM} = 24 \text{ A Peak}$ )	$t_{gt}$	-	1.0	-	$\mu s$

#### DYNAMIC CHARACTERISTICS

Critical Rate-of-Rise of Off-State Voltage ( $V_D = \text{Rated } V_{DRM}, \text{ Gate Open}, \text{ Exponential Waveform}, T_J = 125^{\circ}C$ )	$dv/dt$	10	-	-	$V/\mu s$
Critical Rate-of-Rise of On-State Current $I_G = 150 \text{ mA}$	$di/dt$	-	-	75	$A/\mu s$
					$T_J = 125^{\circ}C$

3. Pulse duration  $\leq 300 \mu s$ , duty cycle  $\leq 2\%$ .
4. Ratings apply for  $t_w = 1 \text{ ms}$ . See Figure 1 for  $I_{TM}$  capability for various durations of an exponentially decaying current waveform.  $t_w$  is defined as 5 time constants of an exponentially decaying current pulse.
5. The gate controlled turn-on time in a crowbar circuit will be influenced by the circuit inductance.

Voltage Current Characteristic of SCR

Symbol	Parameter
$V_{DRM}$	Peak Repetitive Off State Forward Voltage
$I_{DRM}$	Peak Forward Blocking Current
$V_{RRM}$	Peak Repetitive Off State Reverse Voltage
$I_{RRM}$	Peak Reverse Blocking Current
$V_{TM}$	Peak On State Voltage
$I_H$	Holding Current

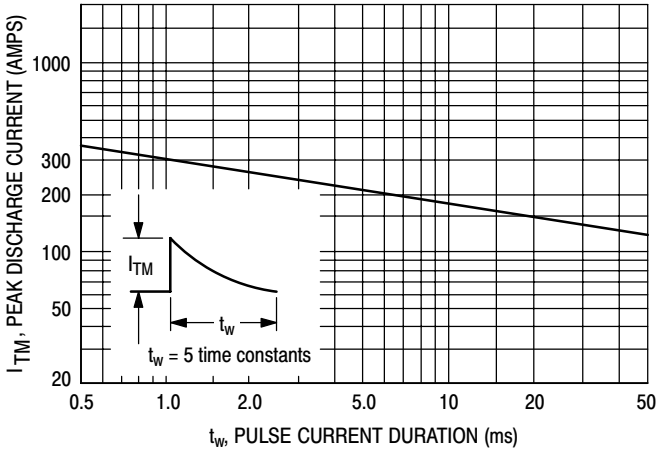
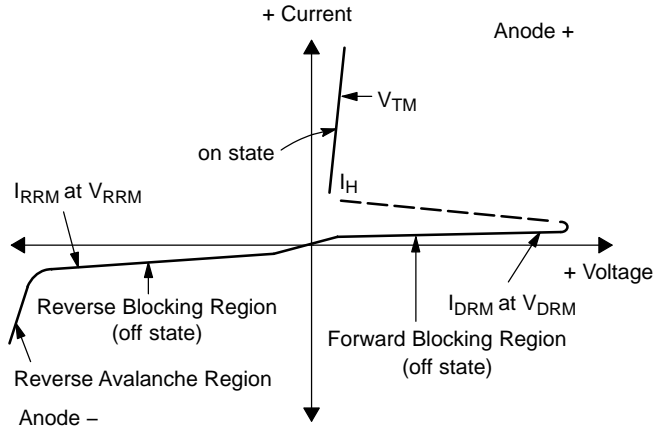


Figure 1. Peak Capacitor Discharge Current

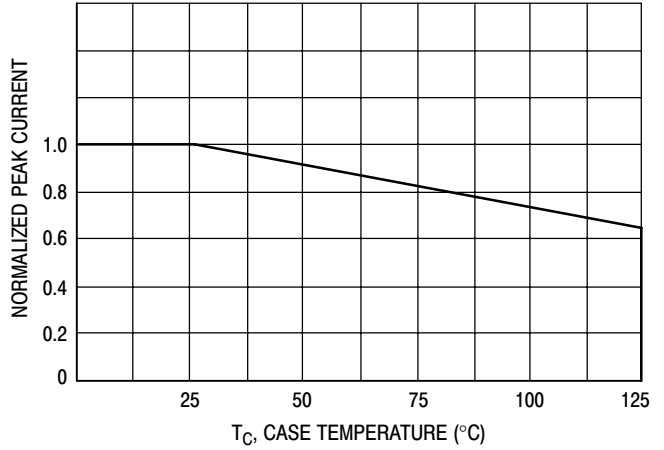


Figure 2. Peak Capacitor Discharge Current Derating

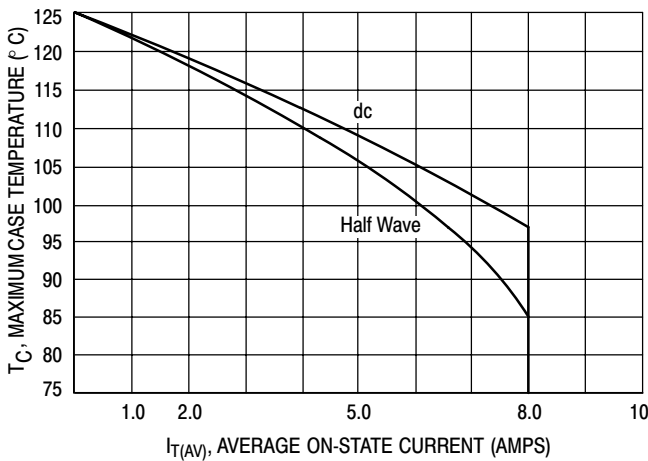


Figure 3. Current Derating

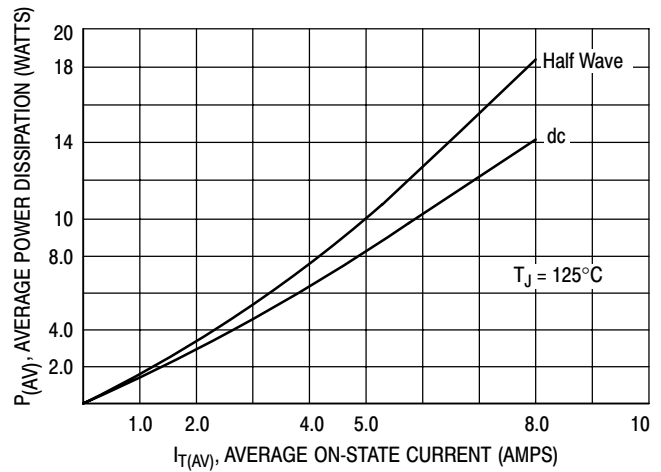


Figure 4. Maximum Power Dissipation

# MCR68-2

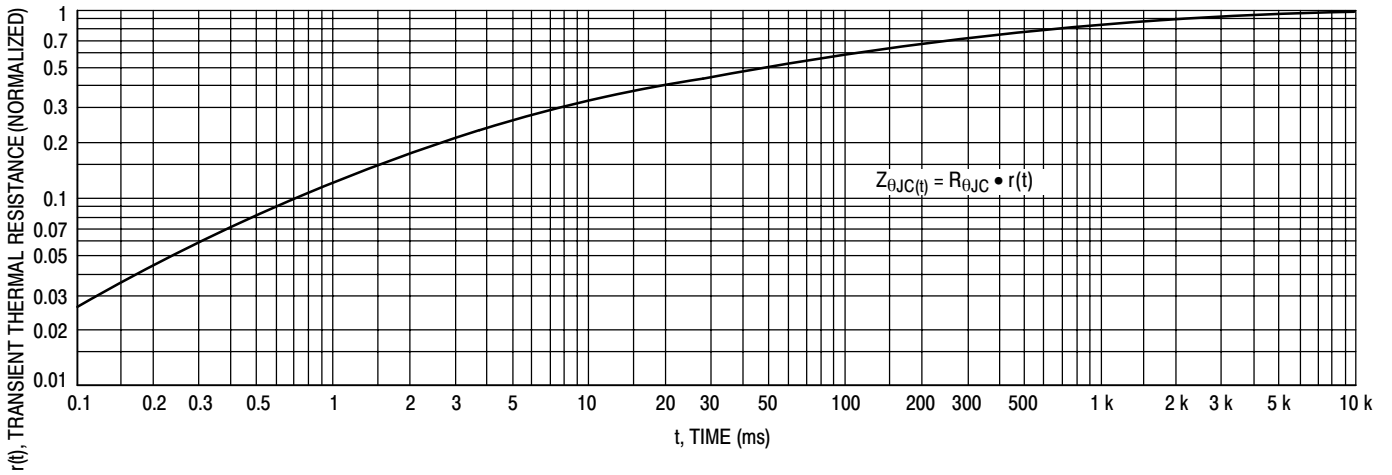


Figure 5. Thermal Response

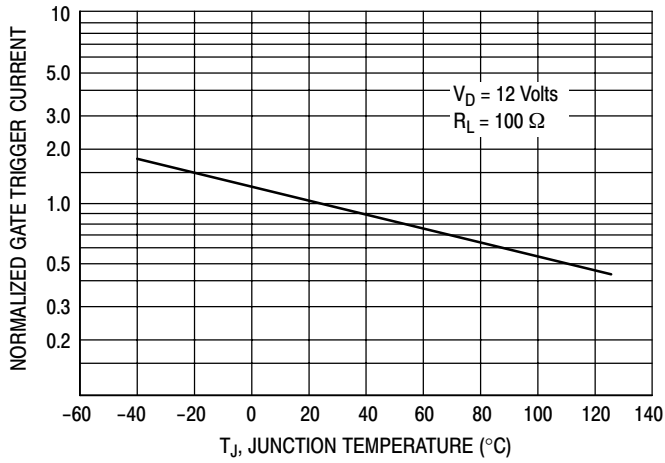


Figure 6. Gate Trigger Current

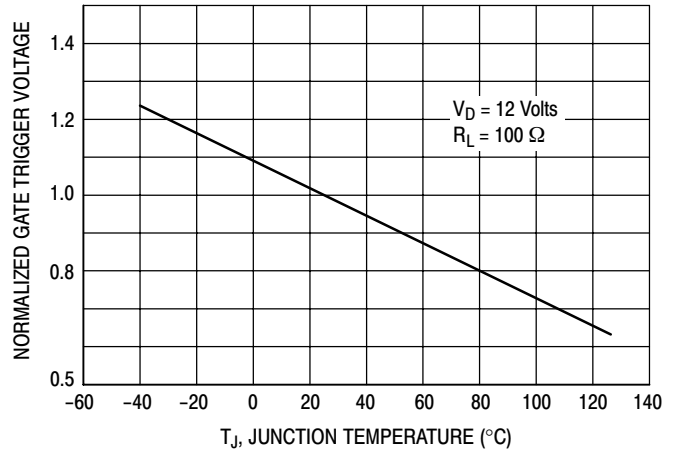


Figure 7. Gate Trigger Voltage

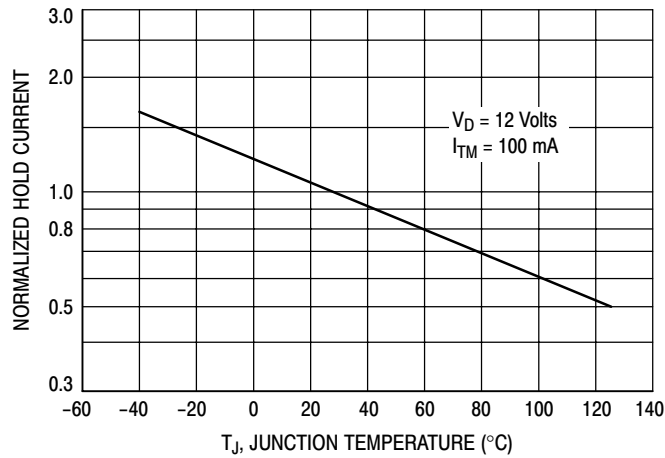
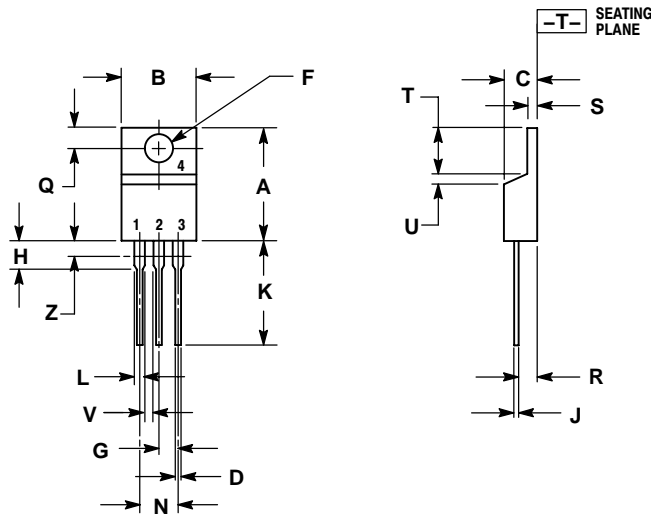


Figure 8. Holding Current

# MCR68-2

## PACKAGE DIMENSIONS

TO-220AB  
CASE 221A-07  
ISSUE AA



**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.014	0.022	0.36	0.55
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	---	0.080	---

**STYLE 3:**

- PIN 1. CATHODE  
2. ANODE  
3. GATE  
4. ANODE

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### PUBLICATION ORDERING INFORMATION

**LITERATURE FULFILLMENT:**  
Literature Distribution Center for ON Semiconductor  
P.O. Box 61312, Phoenix, Arizona 85082-1312 USA  
**Phone:** 480-829-7710 or 800-344-3860 Toll Free USA/Canada  
**Fax:** 480-829-7709 or 800-344-3867 Toll Free USA/Canada  
**Email:** orderlit@onsemi.com

**N. American Technical Support:** 800-282-9855 Toll Free  
USA/Canada

**Japan:** ON Semiconductor, Japan Customer Focus Center  
2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051  
**Phone:** 81-3-5773-3850

**ON Semiconductor Website:** <http://onsemi.com>

**Order Literature:** <http://www.onsemi.com/litorder>

For additional information, please contact your local Sales Representative.

# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[onsemi:](#)

[MCR68-002](#)